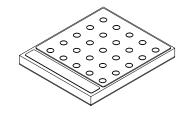
ODB4047UX3.A1

OS-CORE® UX:3



Features:

- Polarity: p-side up

- Chip technology: UX:3

Color: ● blue

- Chipsize: 40 mil x 47 mil

Ordering Information

Type ODB4047UX3.A1-MM-MM-1-C

Ordering Code Q65111A8548



Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T _{op}	min.	-40 °C
		max.	135 °C
Storage Temperature 1)	T_{stg}	min.	-40 °C
	C	max.	135 °C
Recommended Die Storage Temperature ≤ 60% RH	T _{stg die}	max.	30 °C
Junction Temperature	T _j	max.	150 °C
Junction temperature for short time applications*	T _j	max.	175 °C
Forward Current	I _F	min.	20 mA
$T_J = 25 ^{\circ}\text{C}$		max.	3000 mA
Forward Current Pulsed $t \le 10 \ \mu s; \ D = 0.005 \ ; \ T_{_J} = 25 \ ^{\circ}C$	I _{F pulse}	max.	4000 mA
ESD withstand voltage acc. ANSI/ESDA/JEDEC JS-001 (HBM, Class 0)	V_{ESD}		ESD sensitive device
Reverse voltage 2)	V_R		Not designed for reverse operation

^{*}The median lifetime (L70/B50) for Tj =175 $^{\circ}$ C is 100h.

Characteristics

 $I_F = 1000 \text{ mA}; T_J = 25 \text{ }^{\circ}\text{C}$

Parameter	Symbol		Values
Dominant Wavelength ³⁾ I _F = 1000 mA	$\lambda_{\sf dom}$	min. max.	440.0 nm 465.0 nm
Forward Voltage ⁴⁾ I _F = 1000 mA	V_{F}	min. typ. max.	2.80 V 3.00 V 3.35 V

Additional Information

Die bonding	Metalization frontside	Metalization backside
Eutectic bonding	Gold	AuSn



Binning Table 5)3)

 $I_F = 1000 \text{ mA}$

l _e	λ_{dom}
a. u.	nm
	1.10

a. u.	nm 440.0 - 442.5	442.5 - 445.0	445.0 - 447.5	447.5 - 450.0	450.0 - 452.5
230 - 250	A16	B16	C16	D16	E16
250 - 270	A19	B19	C19	D19	E19
270 - 290	A22	B22	C22	D22	E22
290 - 310	A25	B25	C25	D25	E25
310 - 330	A28	B28	C28	D28	E28
330 - 350	A31	B31	C31	D31	E31
350 - 370	A34	B34	C34	D34	E34

l _e		$\lambda_{\sf dom}$
a.	U.	nm

a. u.	nm 452.5 - 455.0	455.0 - 457.5	457.5 - 460.0	460.0 - 465.0	
230 - 250	F16	G16	H16	I16	
250 - 270	F19	G19	H19	I19	
270 - 290	F22	G22	H22	122	
290 - 310	F25	G25	H25	125	
310 - 330	F28	G28	H28	128	
330 - 350	F31	G31	H31	I31	
350 - 370	F34	G34	H34	134	

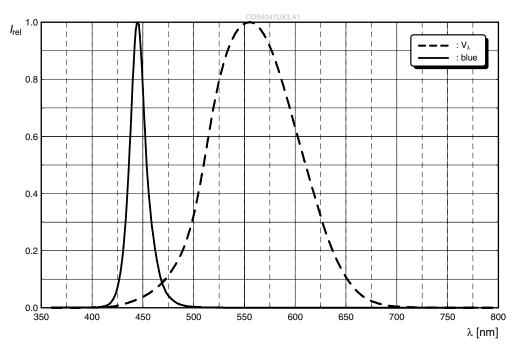
Correlation factor 6)

Unit	Value	Condition
CF (mW/sr / a.u.)	1.6	chip to air
CF (mW / a.u.)	5.5	chip with silicone lens



Relative Spectral Emission 7)

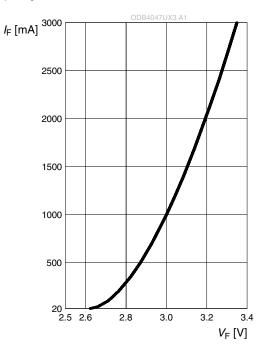
 $I_{rel} = f(\lambda); I_F = 1000 \text{ mA}; T_J = 25 ^{\circ}\text{C}$





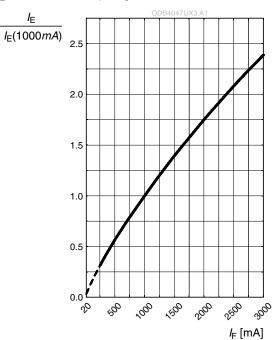
Forward current 7), 8)

$$I_F = f(V_F); T_J = 25 \, ^{\circ}C$$



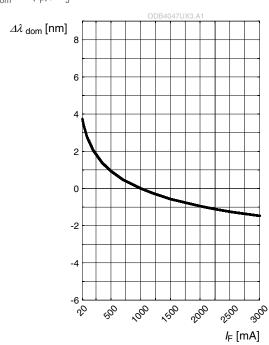
Relative Radiant Intensity 7), 8)

$$I_{E}/I_{E}(1000 \text{ mA}) = f(I_{F}); T_{J} = 25 \text{ }^{\circ}\text{C}$$



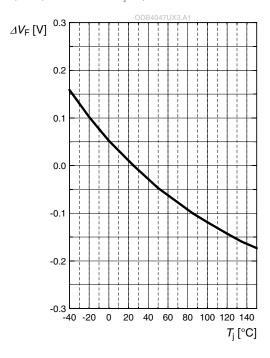
Dominant Wavelength 7)

$$\Delta\lambda_{dom} = f(I_F); T_J = 25 \text{ }^{\circ}\text{C}$$



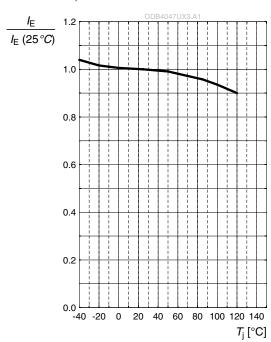
Forward Voltage 7)

$$\Delta V_{_F} = V_{_F} - V_{_F} (25~^{\circ}C) = f(T_{_j}); \ I_{_F} = 1000~mA$$



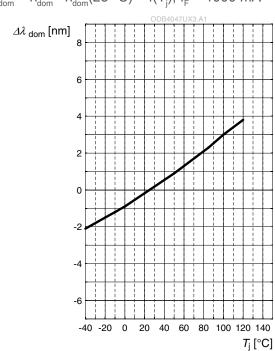
Relative Radiant Intensity 7)

$$I_{E}/I_{E}(25 \text{ °C}) = f(T_{i}); I_{E} = 1000 \text{ mA}$$

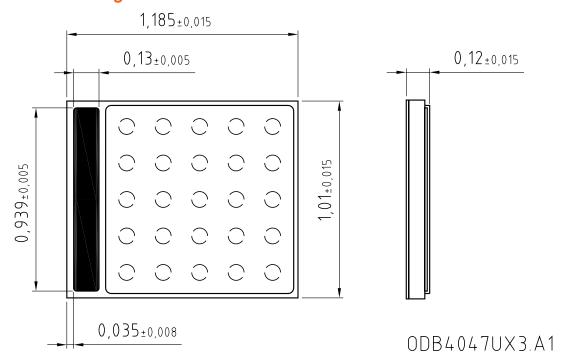


Dominant Wavelength 7)

$$\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \, ^{\circ}C) = f(T_{j}); I_{F} = 1000 \, \text{mA}$$



Dimensional Drawing 9)



Disclaimer

Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

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Glossary

- Shelf life: Temperature refer solely to storage of finished LED product (Not valid for chip on die sheet).
- 2) Reverse Operation: Not designed for reverse operation. Continuous reverse operation can cause migration and damage of the device.
- Wavelength: The wavelength is measured at a current pulse of typically 10 ms and with an internal reproducibility of \pm 1 nm (with a coverage factor of k = 3).
- Forward Voltage: The forward voltage is measured during a current pulse of typically 5 ms and with an internal reproducibility of \pm 0.1 V (with a coverage factor of k = 3).
- 5) Brightness: Brightness values are measured during a current pulse of typically 10 ms and with an internal reproducibility of \pm 8 % (with a coverage factor of k = 3).
- 6) Correlation Factor: The exemplary correlation factor (CF) was estimated by sample build of the chip in a reference package and describes the exemplary correlation between the chip brightness measured in arbitrary units (a.u.) and the brightness in a reference package: $CF = I/\Phi(package) / I(chip)$. This factor is purely given as an indication of possible package brightness values. It may vary for different packages due to influences of geometries, reflectivity/refractive index of package materials or other material properties.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 9) Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.

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